

PRODUCT SPECIFICATION

| | |
|--------------|---|
| Product Name | S76G LoRa and GNSS Wireless Communication Module |
| Version | D |
| Doc No | 901-10601 |
| Date | July 31 ,2018 |



AcSiP Technology Corp.
An IoT Solution Company

3F,-1 No.207,Fusing Rd., Taoyuan City,Taoyuan Dist.,Taoyuan City 33066, Taiwan(R.O.C)
T. +886 3 286-8388 F. +886 3 347-5000

www.acsip.com.tw

Document History

| Date | Revised Contents | Revised By | Version |
|------------------------------|--|------------|---------|
| Nov 01 th , 2017 | Draft Version | Kenny | A |
| Mar 26 th , 2018 | Modify GNSS features description and Package Information | Kenny | B |
| Jun 27 th , 2018 | Electrical Characteristics and pin definitions update and modify product marking to add 2D barcode | Kenny | C |
| July 31 st , 2018 | 1. Correct the function description content, 2. Update Block Diagram, | Kenny | D |

INDEX

| | |
|---|-----------|
| 1. FEATURE..... | 3 |
| 1-1. BLOCK DIAGRAM | 4 |
| 1-2. PRODUCT VERSION..... | 4 |
| 1-3. SPECIFICATION | 5 |
| 2. ELECTRICAL CHARACTERISTICS | 6 |
| 2-1. ABSOLUTE MAXIMUM RATINGS..... | 6 |
| 2-2. RECOMMENDED OPERATING RANGE..... | 6 |
| 2-3. POWER CONSUMPTION CHARACTERISTICS | 6 |
| 2-3.1. 3.3V for LoRa function..... | 6 |
| 2-3.2. 1.8V for GNSS function | 7 |
| 2-4. GPS TCXO CLK_IN(IN BUFFER MODE) | 8 |
| 2-5. MCU RTC LOW-SPEED EXTERNAL CLOCK..... | 8 |
| 2-6. RF CHARACTERISTICS | 9 |
| 2-6.1. RF characteristics for LoRa | 9 |
| 2-6.2. RF characteristics for GNSS receiver | 10 |
| 2-7. DIGITAL CHARACTERISTICS | 11 |
| 2-7.1. DC characteristics | 11 |
| 2-7.2. NRST pin characteristics | 13 |
| 3. PIN DEFINITION..... | 14 |
| ※ FOR DETAILED FUNCTIONS OF PIN DEFINITIONS, PLEASE REFER TO STM32L073 DATASHEET..... | 15 |
| 3-1. PIN ASSIGNMENT | 16 |
| 4. MECHANICAL DIMENSION..... | 17 |
| 5. RECOMMENDED REFLOW PROFILE | 19 |
| 6. SIP MODULE PREPARATION..... | 20 |
| 6-1. HANDLING | 20 |
| 6-2. SMT PREPARATION | 20 |
| 7. PACKAGE INFORMATION | 21 |
| 7-1. PRODUCT MARKING | 21 |
| 7-2. TRAY DIMENSION..... | 22 |
| 8-1. PACKING INFORMATION..... | 23 |
| 8-2. HUMIDITY INDICATOR CARD..... | 23 |

1. Feature

● Platform Features

- ST micro controller: STM32L073Z
- High performance ARM® Cortex®-M0+ 32-bit RISC core operating at a 32 MHz frequency
- 192 Kbytes of Flash memory
- 20 Kbytes of SRAM
- Serial wire debug (SWD) & JTAG
- USB 2.0 full-speed device/host

● LORA Features

- LORA chip: Semtech SX1276
- LoRa Modem
- +20 dBm constant RF output vs. V supply
- Programmable bit rate up to 37500 bps
- High sensitivity: down to -137 dBm
- Excellent blocking immunity
- Preamble detection
- Automatic RF Sense and CAD with ultra-fast AFC
- Payload up to 128 bytes with CRC

● GNSS Features

- GNSS chip: SONY CXD5603GF
- GPS/GLONASS receiver
- Ultra-low power consumption
- Supports SBAS/QZSS

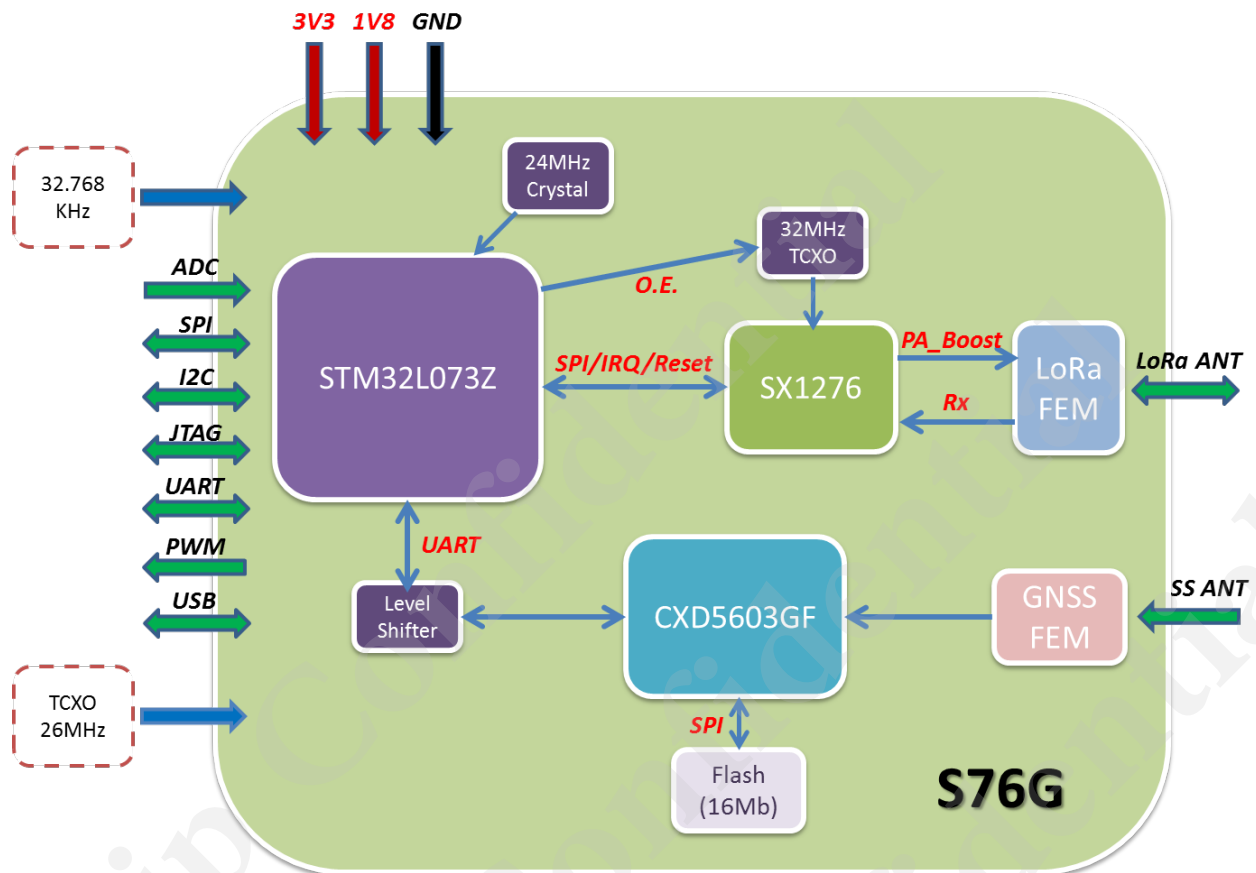
● Other Features

- Periphery components inside S76G:
 1. 24MHz crystal for STM32L073Z and 32MHz TCXO for SX1276
 2. 16Mbits Flash for CXD5603GF
 3. Level shifter for communication between STM32L073Z and CXD5603GF
 4. LoRa FEM/matching circuit and GNSS FEM/matching circuit
- Additional components needed for S76G operation:
 1. 32.768KHz crystal for STM32L073Z
 2. 26MHz TCXO for CXD5603GF
 3. Please see section 2-4 and 2-5 for more details
- Epoxy molding finished module in LGA type
- Small size : 13mm X 11mm X 1.55 mm

● RoHS & Halogen free compliant / Lead free

1-1. Block Diagram

A simplified block diagram of the S76G module is depicted in the figure below.



1-2. Product Version

The features of S76G is detailed in the following table

| Part Number | Frequency Range | Spreading Factor | Bandwidth (K Hz) | Effective Bitrate (bps) | Est. Sensitivity (dBm) |
|-------------|------------------------------|------------------|------------------|-------------------------|--------------------------|
| S76G | 902-928 MHz 863-870 MHz** | 6 - 12 | 62.5 - 500 | 146 - 37500 | -109 to -137* |

Note: * LORA setting SF=12, BW=62.5k, Long-Range Mode, highest LNA gain, *LnaBoost* for Band 1.

**Optional FW Support for European band 868 MHz

1-3. Specification

| Technical Specifications | |
|---------------------------|--|
| Model Name | S76G |
| Product Description | LoRa and GNSS Wireless Communication Module |
| Host Interface | UART |
| Dimension | 13 mm x 11 mm x 1.55mm |
| Package | LGA type |
| Electrical Specifications | |
| Frequency | <ul style="list-style-type: none"> LoRa frequency band: EU868 / US915 / AS923 GNSS frequency band: GPS (L1 C/A) / GLONASS (L1OF) |
| Operation Conditions | |
| Operating Voltage | <ul style="list-style-type: none"> 3.3V for MCU / LoRa function 1.8V for GNSS function |
| Temperature | <ul style="list-style-type: none"> Storage : -50°C ~ +105°C Operating : -25°C ~ +85°C |
| Humidity | <ul style="list-style-type: none"> Operating : 10 ~ 95% (Non-Condensing) Storage : 5 ~ 95% (Non-Condensing) |

2. Electrical Characteristics

2-1. Absolute Maximum Ratings

| Symbol | Parameter | Min. | Typ. | Max. | Unit |
|-----------------|-------------------------------|------|------|------|------|
| VDD_3V3 | Supply Voltage | -0.3 | | 3.9 | V |
| VDD_1V8 | Supply Voltage | -0.3 | | 2.2 | V |
| V _{IN} | Input voltage on digital pins | -0.3 | | 3.9 | V |
| Pmr | LoRa RF Input Level | | | +10 | dBm |

2-2. Recommended Operating Range

| Symbol | Parameter | Min. | Typ. | Max. | Unit |
|---------|---------------------|------|------|------|------|
| VDD_3V3 | Supply Voltage | 2.4 | 3.3 | 3.6 | V |
| VDD_1V8 | Supply Voltage | 1.65 | 1.8 | 1.95 | V |
| ML | LoRa RF Input Level | | | +10 | dBm |

2-3. Power Consumption Characteristics

2-3.1. 3.3V for LoRa function

| Symbol | Parameter | Conditions | Typ. | Max. | Unit |
|--------|---|--|------------------------|------|------|
| IDDSL | Supply current in Sleep mode | Sleep Stop Mode | 4.2 | 5 | uA |
| IDDST | Supply current in Standby mode | TCXO oscillator enabled | 11.2 | 12.8 | mA |
| IDDR | Supply current in Receive mode | | 22.5 | | mA |
| IDDT | Supply current in Transmit mode with impedance matching | RF SetPW = +20 dBm RF SetPW = +17 dBm RF SetPW = +13 dBm RF SetPW = + 7 dBm | 132 112 89 63 | 134 | mA |

2-3.2. 1.8V for GNSS function

| Symbol | Item | State | Typ. | Max. | Unit |
|--------------------|-------------------------------------|------------|------|------|------|
| GNS _{ACQ} | Satellite acquisition | S0: Exec | 20 | 21 | mA |
| GNS _{TRK} | Satellite tracking 8-ch tracking | | 13.1 | 16.5 | mA |
| IDLE | Idle | S1: Idle | 3.6 | | mA |
| SLP ₀ | Sleep0 | S2: Sleep0 | 0.39 | | mA |
| SLP ₁ | Sleep1 | S3: Sleep1 | 0.15 | | mA |

| State | CXD5603GF | | | | |
|------------|-----------|-----------|-----------------|------------|-----------|
| | GNSS | CPU | Always-on block | Backup RAM | Main RAM |
| S0: Exec | Operation | Operation | Operation | Hold | Hold |
| S1: Idle | Standby | Operation | Operation | Hold | Hold |
| S2: Sleep0 | Power-off | Power-off | Operation | Hold | Hold |
| S3: Sleep1 | Power-off | Power-off | Operation | Hold | Power-off |

State Description

S0: Exec

GNSS positioning can be performed.

S1: Idle

This is a command waiting state. The system can accept commands but power consumption is managed to be low.

S2: Sleep0

The CXD5603GF holds program code, data and satellite data but other logic circuit is powered off. The CXD5603GF can wake up from this state without loading the data from an external FLASH memory or the system MCU.

S3: Sleep1

Because the CXD5603GF holds satellite data only in this state, it must load program data from an external FLASH memory or the system MCU for wake-up but it can get a position with hot start.

2-4. GPS TCXO CLK_IN(in buffer mode)

| Item | Symbol | Min. | Typ. | Max. | Unit |
|---------------------------------|-------------|------|------|------|------|
| Input voltage range | V_{IN} | 0.8 | - | 1.4 | Vpp |
| Input Frequency | F_{IN} | - | 26.0 | - | MHz |
| Input frequency characteristics | F_{IN_C} | -0.5 | - | 0.5 | ppm |
| Duty Cycle | D_C | 40 | - | 60 | % |

Recommended Parts List

- Nihon Dempa Kogyo Co., Ltd. / NT2016SA
- KYOCERA Crystal Device Corporation / KT2016

2-5. MCU RTC Low-speed external clock

| Symbol | Parameter | Conditions* | Min | Typ | Max | Unit |
|--------------------|--|--|-----|--------|------|-----------|
| f_{LSE} | LSE oscillator frequency | | - | 32.768 | - | kHz |
| G_m | Maximum critical crystal trans conductance | LSEDRV[1:0]=00 lower driving capability | - | - | 0.5 | $\mu A/V$ |
| | | LSEDRV[1:0]= 01 medium low driving capability | - | - | 0.75 | |
| | | LSEDRV[1:0] = 10 medium high driving capability | - | - | 1.7 | |
| | | LSEDRV[1:0]=11 higher driving capability | - | - | 2.7 | |
| $t_{SU(LSE)}^{**}$ | Startup time | V_{DD} is stabilized | - | 2 | - | s |

* Refer to the note and caution paragraphs below the table, and to the application note AN2867 "Oscillator design guide for ST microcontrollers".

**Guaranteed by characterization results. $t_{SU(LSE)}$ is the startup time measured from the moment it is enabled (by software) to a stabilized 32.768 kHz oscillation is reached. This value is measured for a standard crystal resonator and it can vary significantly with the crystal manufacturer. To increase speed, address a lower-drive quartz with a high- driver mode.

2-6. RF Characteristics

2-6.1. RF characteristics for LoRa

The table below gives the electrical specifications for the transceiver operating with LoRa™ modulation.

Following conditions apply unless otherwise specified:

- Supply voltage = 3.3 V.
- Temperature = 25° C.
- Frequency bands: 915 MHz
- Bandwidth (BW) = 125 kHz.
- Spreading Factor (SF) = 12.
- Error Correction Code (EC) = 4/6.
- Packet Error Rate (PER)= 1%
- CRC on payload enabled.
- Payload length = 64 bytes.
- Preamble Length = 12 symbols (programmed register PreambleLength=8)
- With matched impedances

| LoRa Transmitter (Conductive) | | | | | |
|---|--------------|------|------|------|------|
| Item | Condition | Min. | Typ. | Max. | Unit |
| Frequency Range | Band1 | | 915 | | MHz |
| Tx Pwr Level @Module O/P | PA_BOOST pin | 17.5 | 18.5 | 19.5 | dBm |
| LoRa Receiver (Conductive) | | | | | |
| Item | Condition | Min. | Typ. | Max. | Unit |
| Frequency Range | Band1 | 863 | 915 | 928 | MHz |
| RF sensitivity, (Long-Range Mode, highest LNA gain, LNA boost, 62.5 kHz bandwidth) | SF = 10 | | -133 | | dBm |
| | SF = 11 | | -135 | | dBm |
| | SF = 12 | | -137 | | dBm |
| RF sensitivity, (Long-Range Mode, highest LNA gain, LNA boost, 125 kHz bandwidth) | SF = 7 | | -121 | | dBm |
| | SF = 8 | | -124 | | dBm |
| | SF = 9 | | -127 | | dBm |
| | SF = 10 | | -130 | | dBm |
| | SF = 11 | | -131 | | dBm |
| | SF = 12 | | -134 | | dBm |
| RF sensitivity, (Long-Range Mode, highest LNA gain, LNA boost, 500 kHz bandwidth) | SF = 7 | | -114 | | dBm |
| | SF = 8 | | -117 | | dBm |
| | SF = 9 | | -120 | | dBm |
| | SF = 10 | | -123 | | dBm |
| | SF = 11 | | -126 | | dBm |
| | SF = 12 | | -128 | | dBm |

2-6.2. RF characteristics for GNSS receiver

| Parameter | Description | Performance | Unit |
|--------------------------------|-------------|-------------|-------|
| C/N @-130 dBm | | 41 | dB |
| Position Accuracy @-130 dBm | 2DRMS | 2.5 | Meter |
| TTFF @-130 dBm | Cold start | < 35 | Sec |
| | Hot start | < 1 | Sec |
| Sensitivity | Acquisition | -146 | dBm |
| | Tracking | -158 | dBm |

2-7. Digital Characteristics

2-7.1. DC characteristics

Input voltage levels

| Symbol | Description | Conditions | Min | Typ. | Max | Unit |
|-----------------|------------------------------------|--------------------------|--------------|------|--------------|------|
| V _{IH} | I/O input high level voltage | NRST | 0.7xVDD_3V3 | - | - | V |
| | | BOOT0 | 0.7xVDD_3V3 | - | - | V |
| | | GPIO | 0.7xVDD_3V3 | - | - | V |
| | | GPS_Digital IO | 0.65xVDD_1V8 | - | VDD_1V8+0.3- | V |
| V _{IL} | I/O input low level voltage | NRST | - | - | 0.3xVDD_3V3 | V |
| | | BOOT0 | - | - | 0.14xVDD_3V3 | V |
| | | GPIO | - | - | 0.3xVDD_3V3 | V |
| | | GPS_Digital IO | -0.3 | - | 0.35xVDD_1V8 | V |
| R _{PU} | Weak pull-up Equivalent resistor | V _{IN} = GND | 30 | 45 | 60 | K Ω |
| R _{PD} | Weak pull-down Equivalent resistor | V _{IN} =VDD_3V3 | 30 | 45 | 60 | K Ω |

Output voltage levels

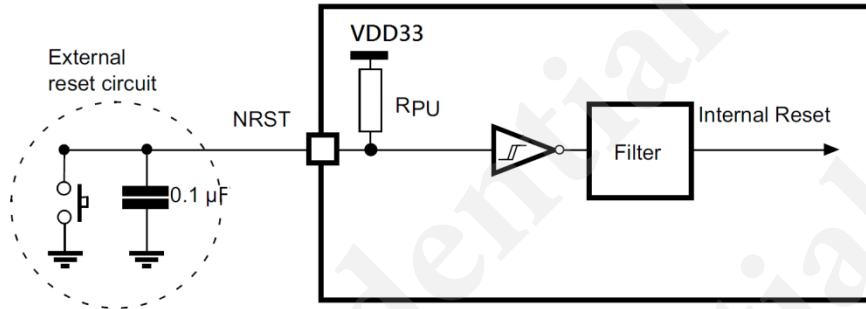
| Symbol | Description | Conditions | Min | Max | Unit |
|----------|--|---|-----------------------|-----------------------|------|
| V_{OL} | Output low level voltage for an I/O pin | CMOS port / IIO = +8 mA $2.7\text{ V} \leq VDD_3V3 \leq 3.6\text{ V}$ | - | 0.4 | V |
| V_{OH} | Output high level voltage for an I/O pin | | $VDD_3V3-0.4$ | - | |
| V_{OL} | Output low level voltage for an I/O pin | TTL port / IIO =+ 8 mA $2.7\text{ V} \leq VDD_3V3 \leq 3.6\text{ V}$ | - | 0.4 | |
| V_{OH} | Output high level voltage for an I/O pin | TTL port / IIO =- 6 mA $2.7\text{ V} \leq VDD_3V3 \leq 3.6\text{ V}$ | 2.4 | - | |
| V_{OL} | Output low level voltage for an I/O pin | IIO = +15 mA $2.7\text{ V} \leq VDD_3V3 \leq 3.6\text{ V}$ | - | 1.3 | |
| V_{OH} | Output high level voltage for an I/O pin | IIO = -15 mA $2.7\text{ V} \leq VDD_3V3 \leq 3.6\text{ V}$ | $VDD_3V3-1.3$ | - | |
| V_{OL} | Output low level voltage for an I/O pin | IIO = +4 mA $1.65\text{ V} \leq VDD_3V3 \leq 3.6\text{ V}$ | - | 0.45 | |
| V_{OH} | Output high level voltage for an I/O pin | IIO = +4 mA $1.65\text{ V} \leq VDD_3V3 \leq 3.6\text{ V}$ | $VDD_3V3-0.45$ | - | |
| V_{OL} | Output low level voltage | GPS_Digital IO | - | $0.2 \times VDD_1V8$ | |
| V_{OH} | Output high level voltage | GPS_Digital IO | $0.8 \times VDD_1V8$ | - | |

2-7.2. NRST pin characteristics

The NRST pin input driver uses CMOS technology.

It is connected to a permanent pull-up resistor (R_{PU}).

The following figure is recommended NRST pin protection circuit against parasitic resets.



| Symbol | Description | Conditions | Min | Typ. | Max | Unit |
|-----------------|---|---|-----|----------------|---------|------------|
| $V_{IL(NRST)}$ | NRST input low level voltage | | VSS | | 0.8 | V |
| $V_{IH(NRST)}$ | NRST input high level voltage | | 1.4 | | VDD_3V3 | V |
| $V_{OL(NRST)}$ | NRST output low level voltage | $I_{OL} = 2\text{mA}$ $2.7\text{V} < \text{VDD_3V3} < 3.6\text{V}$ | | | 0.4 | V |
| $V_{OL(NRST)}$ | NRST output low level voltage | $I_{OL} = 1.5\text{mA}$ $1.65\text{V} < \text{VDD_3V3} < 2.7\text{V}$ | | | 0.4 | V |
| $V_{hys(NRST)}$ | NRST schmitt trigger voltage hysteresis | | | 10% VDD_3V3 | | mV |
| R_{PU} | Weak pull-up Equivalent resistor | $V_{IN} = \text{GND}$ | 30 | 45 | 60 | K Ω |
| V_F | NRST Input filtered pulse | | | | 50 | nS |
| V_{NF} | NRST Input not filtered pulse | $\text{VDD_3V3} > 2.7\text{V}$ | | 350 | | nS |

3. Pin Definition

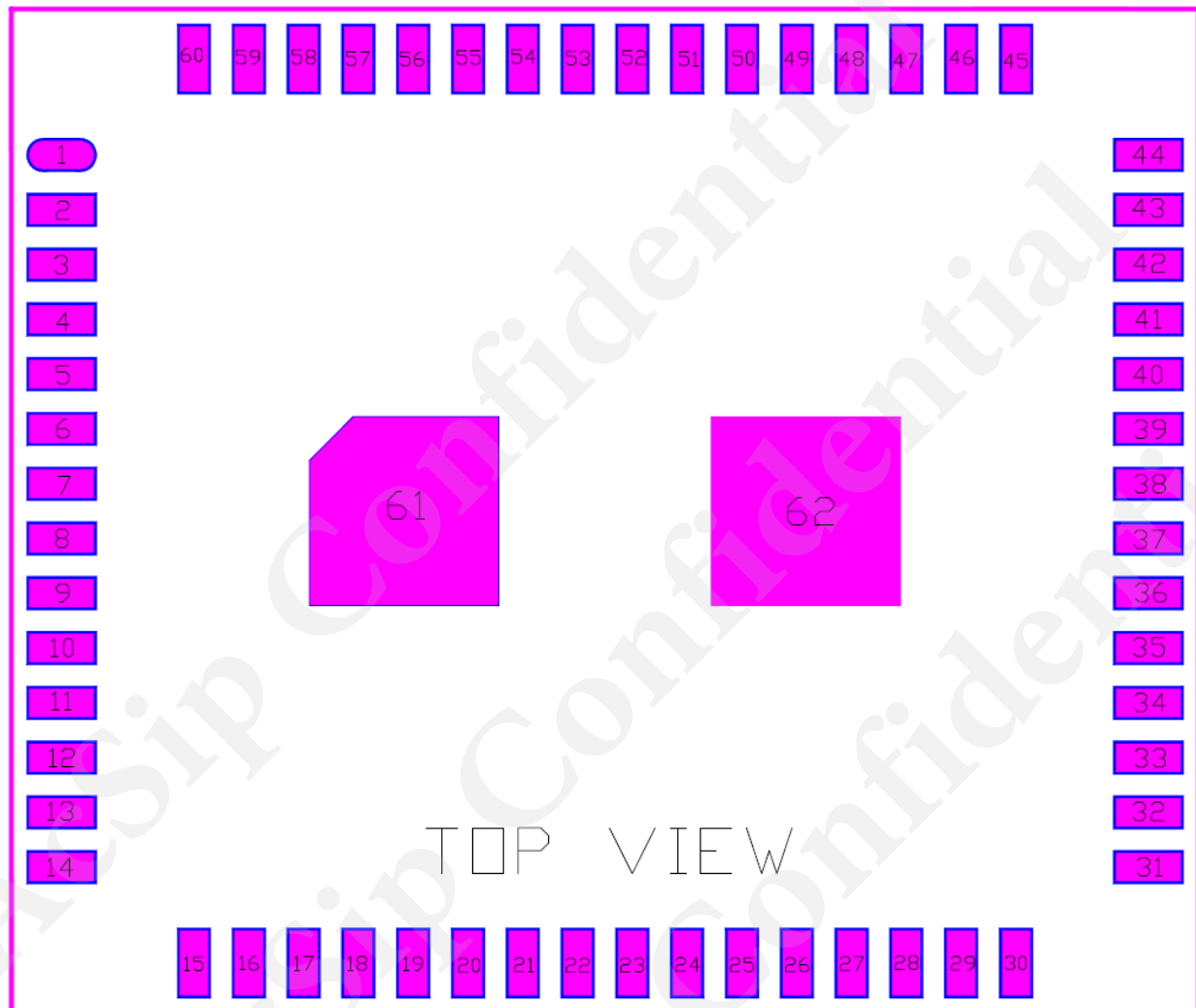
| Pin | Definition | I/O | Power Domain | Description |
|-----|--------------|-----|--------------|--|
| 1 | VDD_3V3 | | VDD_3V3 | Power Supply |
| 2 | GND | | | Ground pin |
| 3 | GND | | | Ground pin |
| 4 | MCU_Reset | I/O | VDD_3V3 | Hardware reset pin |
| 5 | GND | | | Ground pin |
| 6 | OSC32_IN | I/O | | MCU RTC 32.768KHz crystal input |
| 7 | OSC32_OUT | I/O | | MCU RTC 32.768KHz crystal output |
| 8 | GND | | | Ground pin |
| 9 | PA0 | I/O | VDD_3V3 | MCU pin name: PA0 |
| 10 | PA2 | I/O | VDD_3V3 | MCU pin name: PA2 |
| 11 | PA3 | I/O | VDD_3V3 | MCU pin name: PA3 |
| 12 | GND | | | Ground pin |
| 13 | GPS_I2C_SDA | I/O | VDD_1V8 | GPS_I2C bus for sensor |
| 14 | GPS_I2C_SCL | I/O | VDD_1V8 | GPS_I2C bus for sensor |
| 15 | PA4 | I/O | VDD_3V3 | MCU pin name: PA4 |
| 16 | PA5 | I/O | VDD_3V3 | MCU pin name: PA5 |
| 17 | PA6 | I/O | VDD_3V3 | MCU pin name: PA6 |
| 18 | PA7 | I/O | VDD_3V3 | MCU pin name: PA7 |
| 19 | PC4 | I/O | VDD_3V3 | MCU pin name: PC4 |
| 20 | PB0 | I/O | VDD_3V3 | MCU pin name: PB0 |
| 21 | PB1 | I/O | VDD_3V3 | MCU pin name: PB1 |
| 22 | GPS_TCXO_EN | O | VDD_1V8 | GPS 26MHz TCXO enabler |
| 23 | GPS_1PPS_OUT | I/O | VDD_1V8 | Interrupt output / 1PPS out |
| 24 | GPS_RST_X | I | VDD_1V8 | GPS Reset pin, Connect to host is active low reset, |
| 25 | GPS_UART_TXD | I/O | VDD_1V8 | Reserved for GPS Uart_TX test port |
| 26 | GPS_UART_RXD | I/O | VDD_1V8 | Reserved for GPS Uart_RX test port |
| 27 | GND | | | Ground pin |
| 28 | RXTX/RFMOD | I/O | VDD_3V3 | Control signal from SX1276, which connects to internal RF switch at the same time. |
| 29 | GND | | | Ground pin |
| 30 | RF_ANT | I/O | | LoRa RF I/O |

| Pin | Definition | I/O | Power Domain | Description |
|-----|-----------------|-----|--------------|---|
| 31 | PA1_RF_FEM_CPS | O | VDD_3V3 | Control signal from MCU_PA1, which connects to internal RF switch at the same time. |
| 32 | GND | | | Ground pin |
| 33 | NC | | | |
| 34 | GND | | | Ground pin |
| 35 | GND | | | Ground pin |
| 36 | NC | | | |
| 37 | GND | | | Ground pin |
| 38 | NC | | | |
| 39 | GND | | | Ground pin |
| 40 | NC | | | |
| 41 | GND | | | Ground pin |
| 42 | NC | | | |
| 43 | GND | | | Ground pin |
| 44 | GPS_ANT | I | | GPS RF Input |
| 45 | PA8 | I/O | VDD_3V3 | MCU pin name: PA8 |
| 46 | PA9_USART1_TX | I/O | VDD_3V3 | MCU pin name: PA9 |
| 47 | PA10_USART1_RX | I/O | VDD_3V3 | MCU pin name: PA10 |
| 48 | PA11 | I/O | VDD_3V3 | MCU pin name: PA11 |
| 49 | PA12 | I/O | VDD_3V3 | MCU pin name: PA12 |
| 50 | PA13_SWDIO | | VDD_3V3 | Serial wire (SWD) debug interface |
| 51 | PA14_SWCLK | | VDD_3V3 | Serial wire (SWD) debug interface |
| 52 | GPS_TCXO_CLK_IN | I/O | VDD_1V8 | GPS 26MHz Clock input from TCXO |
| 53 | GND | | | Ground pin |
| 54 | VDD_1V8 | | VDD_1V8 | Power Supply |
| 55 | NC | | | |
| 56 | PB5 | I/O | VDD_3V3 | MCU pin name: PB5 |
| 57 | PB6_SCL | I/O | VDD_3V3 | MCU pin name: PB6 |
| 58 | PB7_SDA | I/O | VDD_3V3 | MCU pin name: PB7 |
| 59 | BOOT0 | I | VDD_3V3 | Boot mode selection pin |
| 60 | PB8 | I/O | VDD_3V3 | MCU pin name: PB8 |
| 61 | GND | | | Ground Pin |
| 62 | GND | | | Ground Pin |

※ For detailed functions of pin definitions, please refer to [STM32L073](#) datasheet.

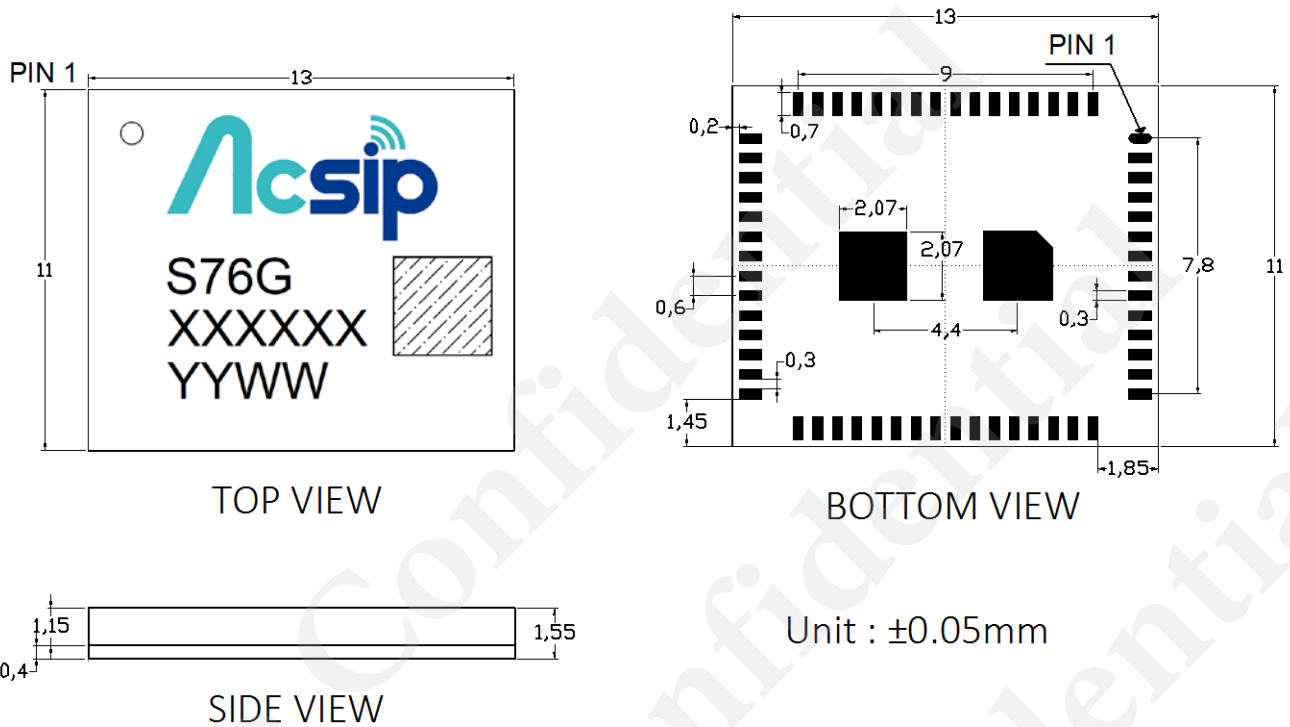
3-1. Pin Assignment

The SiP module will conform to the following pin map, shown in the following diagram (top view)



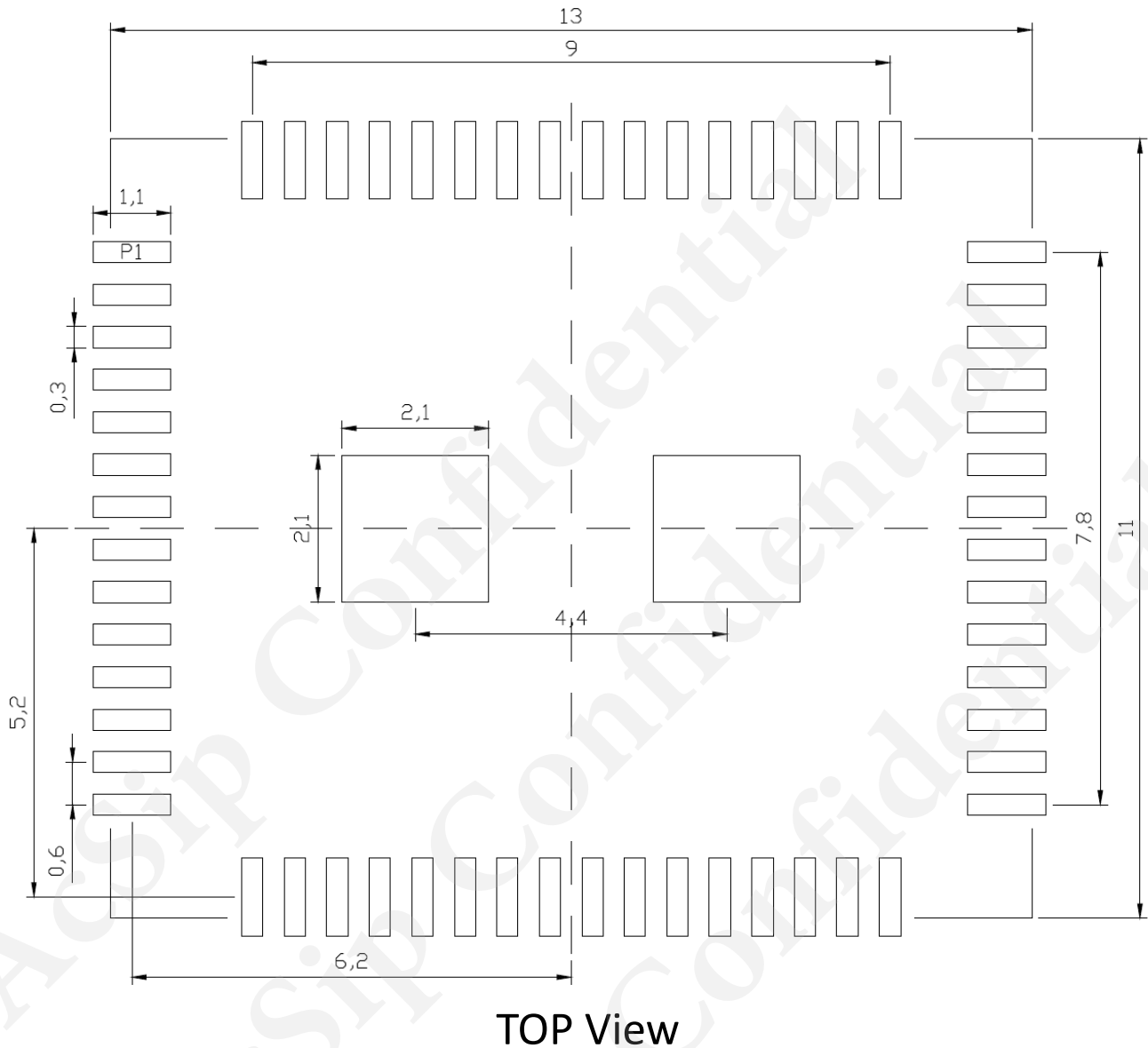
4. Mechanical Dimension

Unit: mm



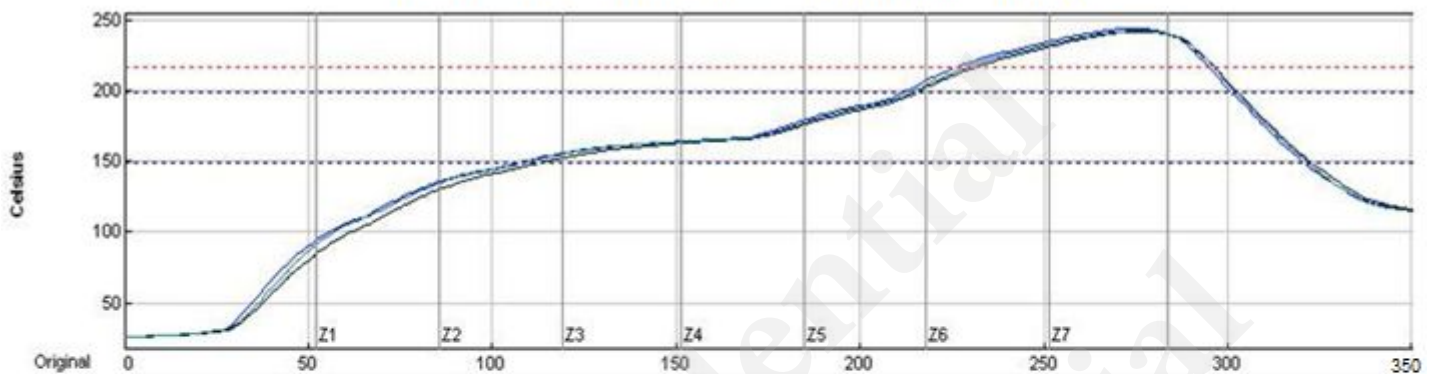
4-1. Recommended Footprint

Unit: mm



5. Recommended Reflow Profile

Reflow Profile for SiP on board Assembly



| | |
|-------------------|---|
| Preheat time | 150°C—200°C : 105+/-15sec |
| Dwell time | Over 220°C : 70+5/-10 sec |
| Peak Temp | 240 +10/-5°C |
| Ramp Up/Down Rate | Up: 3 +0/-2 °C / sec Down: 2 +0/-1°C / sec |

6. SiP Module Preparation

6-1. Handling

Handling the module must wear the anti-static wrist strap to avoid ESD damage. After each module is aligned and tested, it should be transport and storage with anti -static tray and packing. This protective package must be remained in suitable environment until the module is assembled and soldered onto the main board.

6-2. SMT Preparation

1. Calculated shelf life in sealed bag: 6 months at <40°C and <90% relative humidity (RH).
2. Peak package body temperature: 250°C.
3. After bag was opened, devices that will be subjected to reflow solder or other high temperature process must.
 - A. Mounted within: 168 hours of factory conditions <30°C /60%RH.
 - B. Stored at $\leq 10\%$ RH with N2 flow box.
4. Devices require baking, before mounting, if:
 - A. Package bag does not keep in vacuumed while first time open.
 - B. Humidity Indicator Card is >10% when read at 23±5°C.
- C. Expose at 3A condition over 8 hours or Expose at 3B condition over 24 hours.
5. If baking is required, devices may be baked for 12 hours at 125±5°C.

7.Package Information

7-1. Product Marking

Figure 1 below details the standard product marking for all AcSiP Corp. products. Cross reference to the applicable line number and table for a full detail of all the variables.

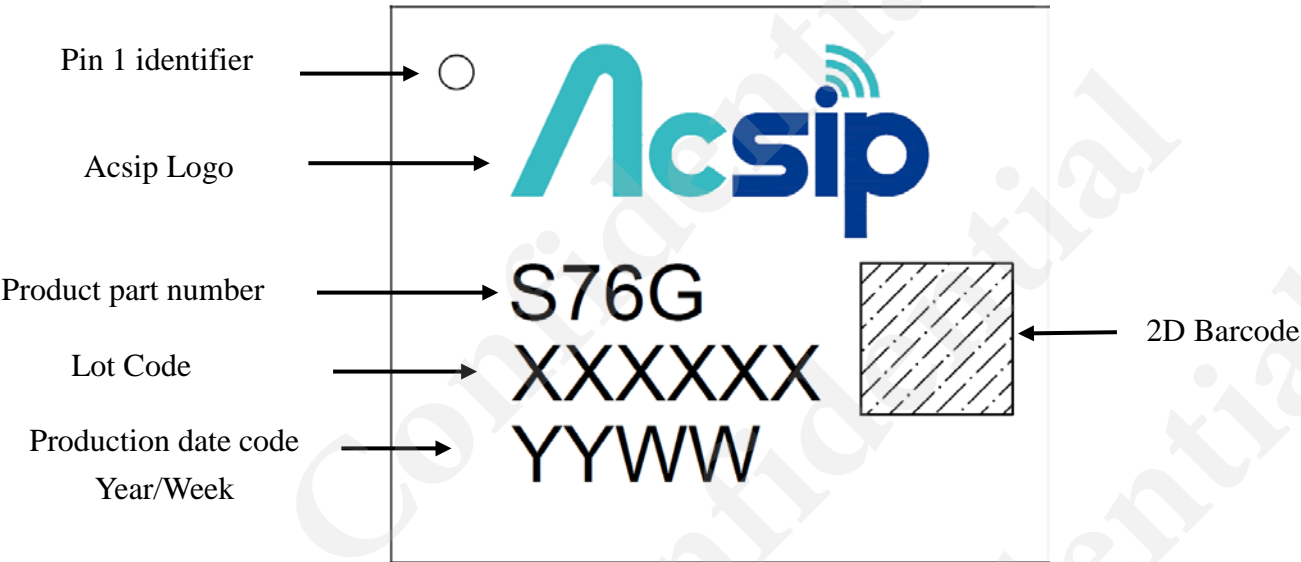
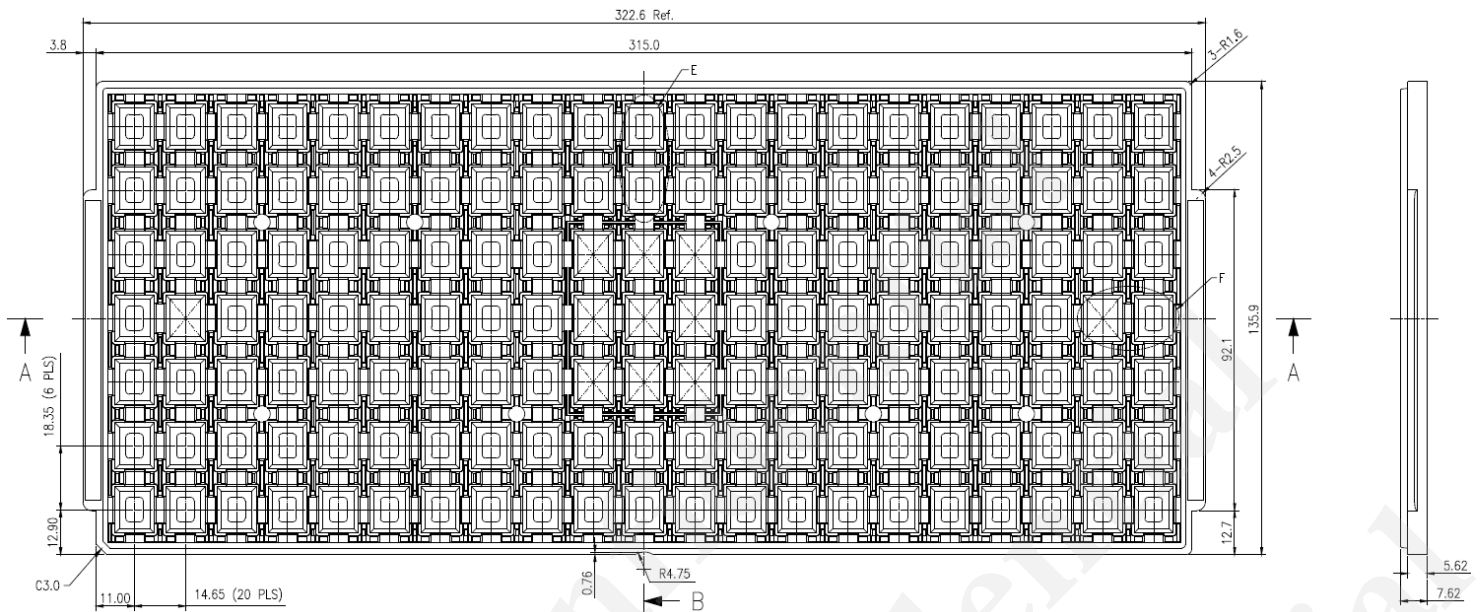


Figure 1 Standard Product Marking Diagram- TOP VIEW

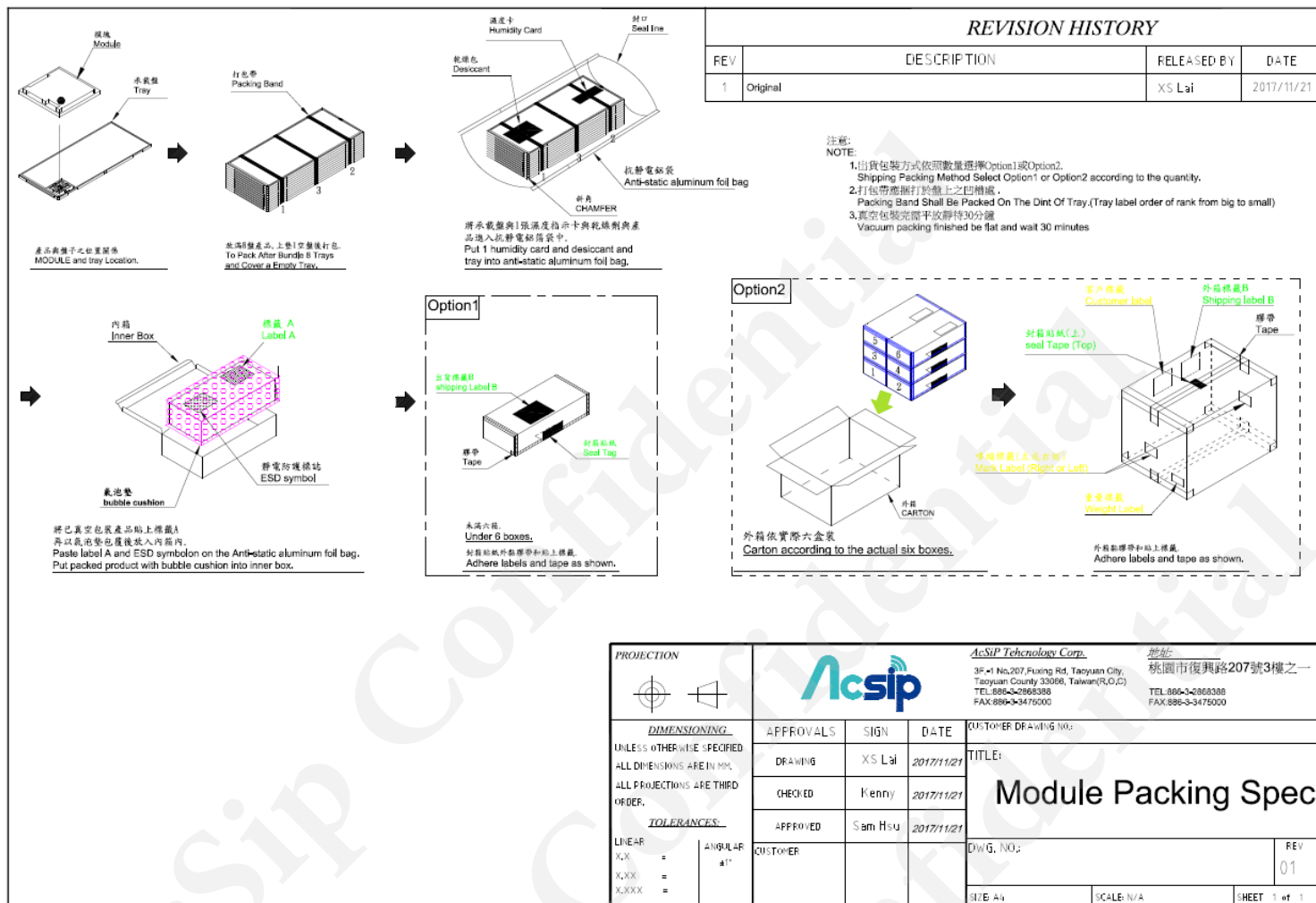


7-2. Tray Dimension

Unit: mm



8-1. Packing Information



8-2. Humidity Indicator Card



Dry

Wet

Indicates 指示點:

10%,20%,30,40%,50%,60% relative humidity

10%,20%,30,40%,50%,60% 相對濕度

Color Change 顏色變化:

Brown (Dry) ---> Blue (Wet)

棕色(乾燥) → 藍色(潮溼)